NSN 5962-01-430-2308

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-430-2308

View Offiline at https://derobasegroup.com/histi/0302-01-430-2300
Body Length:
Between 0.816 inches and 0.838 inches
Body Width:
Between 0.430 inches and 0.445 inches
Body Height:
Between 0.088 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5895-01-412-4427
Features Provided:
Monolithic and electrostatic sensitive and low power and burn in, mil-std-883, class b
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
35.00 nanoseconds input to output access
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 j-hook
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

NSN 5962-01-430-2308

Memory Microcircuit - Page 2 of 2



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